## Bipolar Junction Transistor (BJT)

## BJT as Amplifier

## Coupling Capacitor



For a coupling capacitor to work properly, its reactance must be much smaller than the resistance at the lowest frequency of the ac source.

$$
\text { Good coupling: } X_{C}<0.1 R
$$

## Base biased Amplifier circuit with waveform



Voltage gain : $\quad A_{V}=\frac{v_{\text {out }}}{v_{\text {in }}}$

## VDB Amplifier circuit with waveform



Bypass Capacitor: A bypass capacitor is similar to a coupling capacitor because it appears open to direct current and shorted to alternating current. But it is not used to couple a signal between two points. Instead, it is used to create an ac ground.

## Small-Signal Operation



When an ac voltage is coupled into the base of a transistor, an ac voltage appears across the base-emitter diode. The ac emitter current is not a perfect replica of the ac base voltage because of the curvature of the graph.
Since the graph is curved upward, the positive half-cycle of the ac emitter current is elongated (stretched) and the negative halfcycle is compressed. This stretching and compressing of alternate half-cycles is called distortion. One way to reduce distortion in Fig. 8-10 is by keeping the ac base voltage small.

## AC Beta:

$$
\beta=\frac{i_{c}}{i_{b}}
$$



AC resistance of emitter diode: $r_{e}{ }^{\prime}=\frac{v_{b e}}{i_{e}}$
Using solid-state physics and calculus, it is possible to derive the following remarkable formula for the ac emitter resistance:

$$
r_{e}^{\prime}=\frac{25 \mathrm{mV}}{I_{E}}
$$



## Graphical analysis of transistor amplifier



## Common Base mode





## Two stage RC coupled amplifier



When an AC input signal is applied to the base of first transistor, it gets amplified and appears at the collector load $R_{L}$ which is then passed through the coupling capacitor $C_{c}$ to the next stage. This becomes the input of the next stage, whose amplified output again appears across its collector load.

## Frequency Response of RC Coupled Amplifier



Capacitive reactance is low at high frequencies. So, a capacitor behaves as a short circuit, at high frequencies. As a result of this, the loading effect of the next stage increases, which reduces the voltage gain. Along with this, as the capacitance of emitter diode decreases, it increases the base current of the transistor due to which the current gain ( $\beta$ ) reduces. Hence the voltage gain rolls off at high frequencies.

## Differential Amplifier with load resistor $\left(\mathbf{R}_{\mathrm{L}}\right)$



## Two Transistor Models

To analyze the ac operation of a transistor amplifier, we need an acequivalent circuit for a transistor.

## T Model - Ebers-Moll model

Replacing transistor by a $T$-model - looks like ' $T$ '


For small ac signal, the emitter diode of a transistor acts like an ac resistance $r_{e}$ ' and the collector diode acts like a current source $i_{c}$.


Looking into the base of the transistor, the ac voltage source sees an input impedance $\mathrm{z}_{\text {in(base) }}$. At low frequencies, this impedance is purely resistive and defined as: $\mathrm{z}_{\text {in(base) }}=v_{b e} / i_{b}$
Applying Ohm's law to the emitter diode, we can write:
$v_{b e}=i_{e} r_{e}{ }^{\prime}$.
So, $\mathrm{z}_{\text {in(base })}=v_{b e} / i_{b}=i_{e} r_{e}{ }^{\prime} / i_{b}$
As $i_{e} \approx i_{c}, \mathrm{z}_{\mathrm{in}(\mathrm{base})}=\beta r_{e}{ }^{\prime}$

## The $\pi$ Model



It's the visual representation of the equation derived earlier $\left(\mathrm{z}_{\text {in(base })}=\beta r_{e}{ }^{\prime}\right)$.
The model is easier to use than the T model because the input impedance is not obvious when we look at the T model. On the other hand, the $\pi$ model clearly shows that an input impedance of $\beta r_{e}{ }^{\text {' }}$ will load the ac voltage source driving the base.

## AC effect of a DC Voltage Source



DC voltage source is an AC short - Because a dc voltage source has a constant voltage across it. Therefore, any ac current flowing through it cannot produce an ac voltage across it.

## Hybrid (h) parameters



Of these four variables $\mathrm{V}_{1}, \mathrm{~V}_{2}, \mathrm{i}_{1}$ and $\mathrm{i}_{2}$, two can be selected as independent variables and the remaining two can be expressed in terms of these independent variables.

If the input current $i_{1}$ and output Voltage $V_{2}$ are takes as independent variables,
Then input voltage $V_{1}$ and output current $i_{2}$ can be written as:

$$
\begin{aligned}
& \mathbf{V}_{1}=\mathbf{h}_{11} \mathbf{i}_{1}+\mathbf{h}_{12} \mathbf{V}_{2} \\
& \mathbf{i}_{2}=\mathbf{h}_{21} \mathbf{i}_{1}+\mathbf{h}_{22} \mathbf{V}_{2}
\end{aligned}
$$

The four hybrid parameters : $\mathrm{h}_{11}, \mathrm{~h}_{12}, \mathrm{~h}_{21}$ and $\mathrm{h}_{22}$ are defined as follows.

- $\mathrm{h}_{11}=\left[\mathrm{V}_{1} / \mathrm{i}_{1}\right]$ with $\mathrm{V}_{2}=0$, : Input resistance with output port short circuited.
- $\mathrm{h}_{12}=\left[\mathrm{V}_{1} / \mathrm{V}_{2}\right]$ with $\mathrm{i}_{1}=0$, : reverse voltage gain with $\mathrm{i} / \mathrm{p}$ port open circuited.
- $h_{21}=\left[i_{2} / i_{1}\right]$ with $V_{2}=0$, : Forward current gain with output part short circuited.
- $h_{22}=\left[i_{2} / V_{2}\right]$ with $i_{1}=0$, : Output admittance with input part open circuited.
$h_{11}-\Omega$,
$h_{12}$ - dimension less,
$h_{21}$-dimension less, $h_{22}$ - siemens


## h parameters of CET

$$
\begin{array}{cc}
\begin{array}{c}
h_{i e}=\frac{\partial v_{i}}{\partial i_{i}}=\left.\frac{\partial v_{b e}}{\partial i_{b}} \cong \frac{\Delta v_{b e}}{\Delta i_{b}}\right|_{V_{C E}=\text { constant }}
\end{array} & \text { (ohms) } \\
h_{r e}=\frac{\partial v_{i}}{\partial v_{o}}=\left.\frac{\partial v_{b e}}{\partial v_{c e}} \cong \frac{\Delta v_{b e}}{\Delta v_{c e}}\right|_{I_{B}=\text { constant }} & \text { (unitless) } \\
h_{f e}=\frac{\partial i_{o}}{\partial i_{i}}=\left.\frac{\partial i_{c}}{\partial i_{b}} \cong \frac{\Delta i_{c}}{\Delta i_{b}}\right|_{V_{C E}=\text { constant }} & \text { (unitless) } \\
h_{o e}=\frac{\partial i_{o}}{\partial v_{o}}=\left.\frac{\partial i_{c}}{\partial v_{c e}} \cong \frac{\Delta i_{c}}{\Delta v_{c e}}\right|_{I_{B}=\text { constant }} \quad \text { (siemens) }
\end{array}
$$

